September 1983 Revised September 2001 MM74HC589 8-Bit Shift Registers with Input Latches and 3-STATE Serial Output

FAIRCHILD

SEMICONDUCTOR

MM74HC589 8-Bit Shift Registers with Input Latches and 3-STATE Serial Output

General Description

The MM74HC589 high speed shift register utilizes advanced silicon-gate CMOS technology to achieve the high noise immunity and low power consumption of standard CMOS integrated circuits, as well as the ability to drive 15 LS-TTL loads.

The MM74HC589 comes in a 16-pin package and consists of an 8-bit storage latch feeding a parallel-in, serial-out 8bit shift register. Data can also be entered serially the shift register through the SER pin. Both the storage register and shift register have positive-edge triggered clocks, RCK and SCK, respectively. SLOAD pin controls parallel LOAD or serial shift operations for the shift register. The shift register has a 3-STATE output to enable the wire-ORing of multiple devices on a serial bus.

The 74HC logic family is speed, function, and pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to $\rm V_{CC}$ and ground.

Features

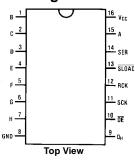
- 8-bit parallel storage register inputs
- Wide operating voltage range: 2V–6V
- Shift register has direct overriding load
- Guaranteed shift frequency. . . DC to 30 MHz
- Low quiescent current: 80 µA maximum (74HC Series)
- 3-STATE output for 'Wire-OR'

Ordering Code:

Order Number	Package Number	Package Description
MM74HC589M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC589SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC589N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

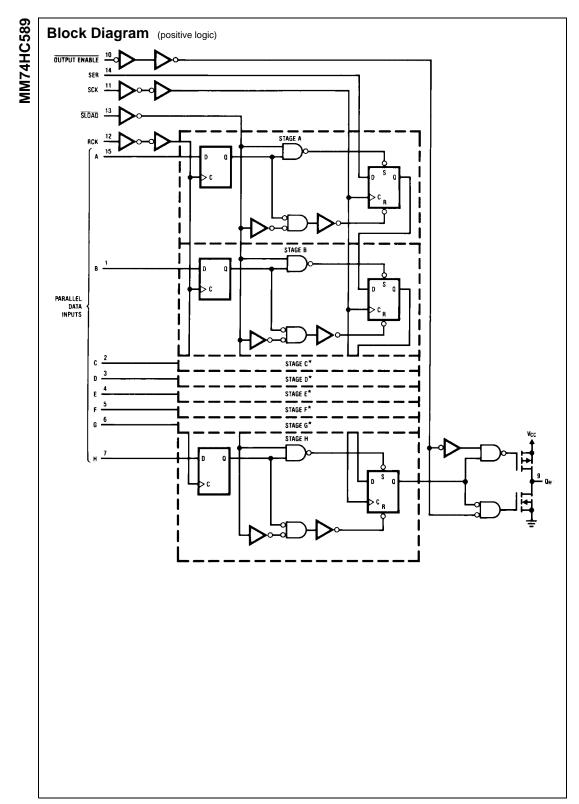
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Truth Table

RCK	SCK	SLOAD	OE	Function
Х	Х	х	Н	Q _H in Hi-Z State
Х	Х	Х	L	Q _H is enabled
Ŷ	Х	Х	Х	Data loaded into input latches
Ŷ	Х	L	Х	Data loaded into shift register
				from pins
H or L	Х	L	Х	Data loaded from latches to
				shift register
Х	Ŷ	н	Х	Shift register is shifted. Data
				on SER pin is shifted in.
Ŷ	Ŷ	Н	Х	Data is shifted in shift register,
				and data is loaded into latches



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Absolute Maximum Ratings(Note 1)

Recommended Operating Conditions

(Note 2)	
Supply Voltage (V _{CC})	-0.5 to +7.0V
DC Input Voltage (V _{IN})	–1.5 to $V_{CC}\text{+1.5V}$
DC Output Voltage (V _{OUT})	–0.5 to V_{CC} +0.5V
Clamp Diode Current (I _{IK} , I _{OK})	±20 mA
DC Output Current, per pin (I _{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I _{CC})	±50 mA
Storage Temperature Range (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T _L)	
(Soldering 10 seconds)	260°C

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
DC Input or Output Voltage			
(V _{IN} , V _{OUT})	0	V _{CC}	V
Operating Temperature Range (T_A)	-40	+85	°C
Input Rise or Fall Times			
$(t_r, t_f) V_{CC} = 2.0 V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns
Note 1: Absolute Maximum Ratings are those age to the device may occur.	values be	yond whic	h dam-

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: – 12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	v _{cc}	$T_A = 25^{\circ}C$		$T_A = -40$ to 85°C $T_A = -55$ to 125°C		Units
Symbol	Falameter	Conditions	•cc	Тур		Guaranteed L	imits	Units
V _{IH}	Minimum HIGH Level		2.0V		1.5	1.5	1.5	V
	Input Voltage		4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
VIL	Maximum LOW Level		2.0V		0.5	0.5	0.5	V
	Input Voltage		4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V _{OH}	Minimum HIGH Level	$V_{IN} = V_{IH} \text{ or } V_{IL}$						
	Output Voltage	$ I_{OUT} \le 20 \ \mu A$	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$						
		I _{OUT} ≤ 6.0 mA	4.5V		3.98	3.84	3.7	V
		I _{OUT} ≤ 7.8 mA	6.0V		5.48	5.34	5.2	V
V _{OL}	Maximum LOW Level	$V_{IN} = V_{IH} \text{ or } V_{IL}$						
	Output Voltage	$ I_{OUT} \le 20 \ \mu A$	2.0V	0	0.1	0.1	0.1	V
			4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		$V_{IN} = V_{IH} \text{ or } V_{IL}$						
		I _{OUT} ≤ 6.0 mA	4.5V		0.26	0.33	0.4	V
		$ I_{OUT} \le 7.8 \text{ mA}$	6.0V		0.26	0.33	0.4	V
I _{IN}	Maximum Input	$V_{IN} = V_{CC}$ or GND	6.0V		±0.1	±1.0	±1.0	μΑ
	Current							
I _{CC}	Maximum Quiescent	$V_{IN} = V_{CC}$ or GND	6.0V		8.0	80	160	μA
	Supply Current	$I_{OUT} = 0 \ \mu A$						
l _{oz}	Maximum 3-STATE	Output in High	6.0V		±0.5	±5.0	±10.0	μA
	Leakage Current	Impedance State						
		$V_{IN} = V_{IL} \text{ or } V_{IH}$						
		$V_{OUT} = V_{CC}$ or GND						
		$\overline{OE} = V_{IH}$						

Note 4: For a power supply of 5V \pm 10% the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC}=5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

MM74HC589

AC Electrical Characteristics

Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
f _{MAX}	Maximum Operating Frequency for SCK		50	30	MHz
t _{PHL} , t _{PLH}	Maximum Propagation Delay from SCK to QH'			30	ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from $\overline{\text{SLOAD}}$ to $\text{Q}_{\text{H}'}$			30	ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay from LCK to QH'	SLOAD = logic "0"	25	45	ns
t _{PZH} , t _{PZL}	Output Enable Time	$R_L = 1 k\Omega$	18	28	ns
t _{PHZ} , t _{PLZ}	Output Disable Time	$R_L = 1 \text{ k}\Omega, C_L = 5 \text{ pF}$	19	25	ns
t _S	Minimum Setup Time from RCK to SCK		10	20	ns
t _S	Minimum Setup Time from SER to SCK		10	20	ns
t _S	Minimum Setup Time from Inputs A thru H to RCK		10	20	ns
t _H	Minimum Hold Time		0	5	ns
t _W	Minimum Pulse Width SCK, RCK, SLOAD		8	16	ns

AC Electrical Characteristics

 V_{CC} = 2.0–6V, C_L = 50 pF, t_r = t_f = 6 ns (unless otherwise specified)

Symbol	Parameter	Conditions	Vcc	$T_A = 25^{\circ}C$		$T_{A}=-40$ to $85^{\circ}C$	Units	
Symbol	Falameter	Conditions	•00	Тур	Guaranteed Limits			
f _{MAX}	Maximum Operating		2.0V		6	4.8	4	MHz
	Frequency for SCK		4.5V		30	24	20	MHz
			6.0V		35	28	24	MHz
t _{PHL} , t _{PLH}	Maximum Propagation		2.0V	62	175	220	265	ns
	Delay from SCK or		4.5V	20	35	44	53	ns
	SLOAD to Q _H		6.0V	18	30	37	45	ns
t _{PHL} , t _{PLH}	Maximum Propagation		2.0V	120	225	280	340	ns
	Delay from SCK or	C _L = 150 pF	4.5V	31	45	56	68	ns
	SLOAD to Q _H		6.0V	28	38	48	58	ns
t _{PHL} , t _{PLH}	Maximum Propagation		2.0V	80	210	265	315	ns
	Delay from RCK to Q _H		4.5V	25	42	53	63	ns
			6.0V	21	36	45	54	ns
t _{PHL} , t _{PLH}	Maximum Propagation		2.0V	80	210	265	313	ns
	Delay RCK to Q _H	C _L = 150 pF	4.5V	25	52	66	77	ns
			6.0V	21	44	56	66	ns
t _{PZH} , t _{PZL}	Output Enable Time	$R_L = 1 k\Omega$	2.0V	70	150	189	224	ns
		-	4.5V	22	30	38	45	ns
			6.0V	20	26	32	38	ns
t _{PHZ} , t _{PLZ}	Output Disable Time	$R_L = 1 k\Omega$	2.0V	70	150	189	224	ns
			4.5V	22	30	38	45	ns
			6.0V	20	26	32	38	ns
ts	Minimum Setup Time		2.0V		100	125	150	ns
-	from RCK to SCK		4.5V		20	25	30	ns
			6.0V		17	22	25	ns
ts	Minimum Setup Time		2.0V		100	125	150	ns
-	from SER to SCK		4.5V		20	25	30	ns
			6.0V		17	22	25	ns
ts	Minimum Setup Time		2.0V		100	125	150	ns
	from Inputs A thru H		4.5V		20	25	30	ns
	to RCK		6.0V		17	22	25	ns
t _H	Minimum Hold Time		2.0V	-5	5	5	5	ns
			4.5V	0	5	5	5	ns
			6.0V	1	5	5	5	ns
t _W	Minimum Pulse Width		2.0V	30	80	100	120	ns
	SCK, RCK, SLOAD,		4.5V	9	16	20	24	ns
	SLOAD		6.0V	8	14	17	20	ns

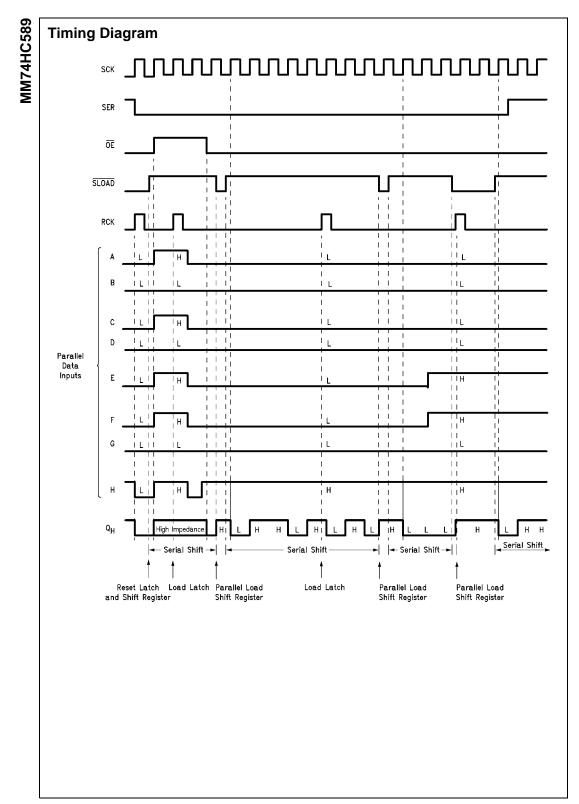
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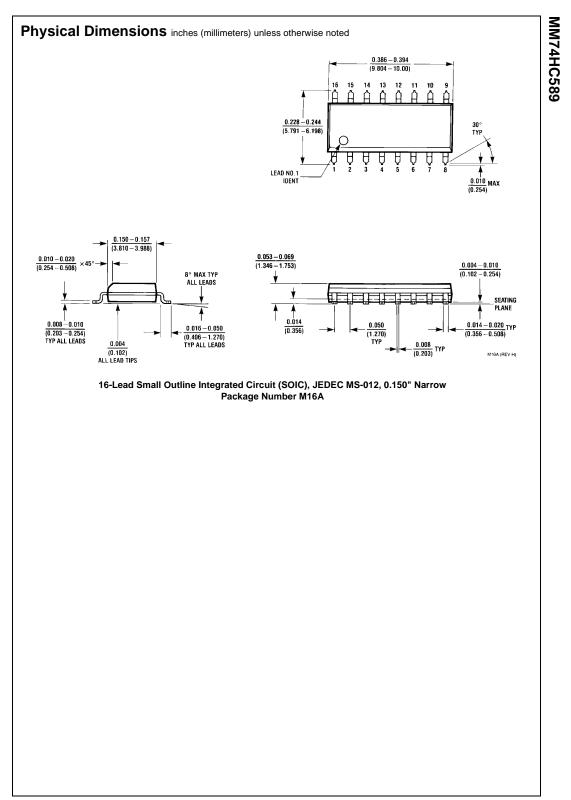
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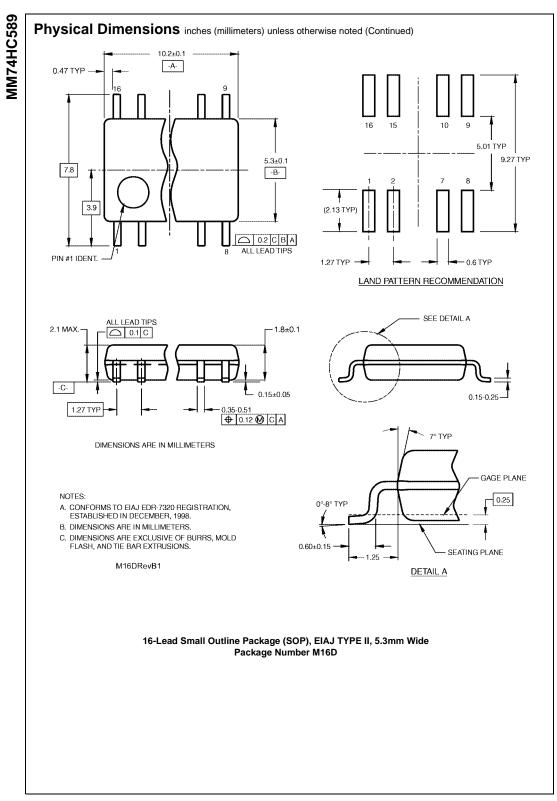
AC Electrical Characteristics (Continued)

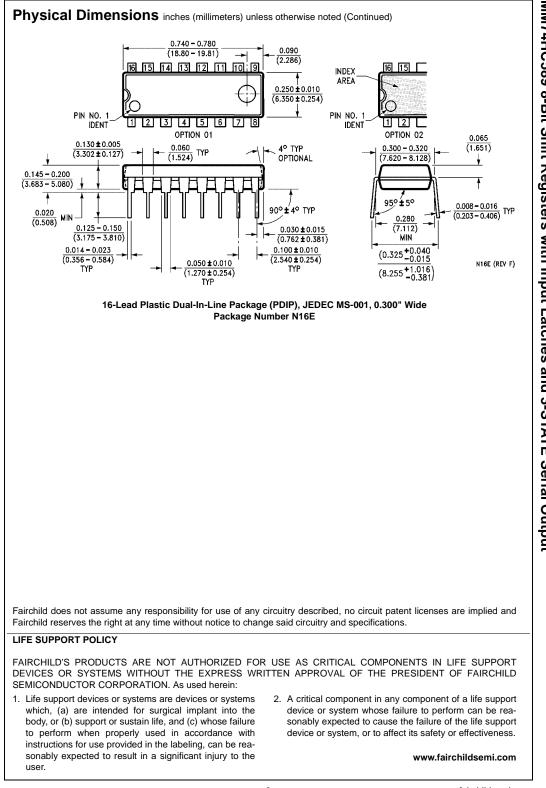
Symbol	Parameter	Conditions	v _{cc}	$T_A = 25^{\circ}C$		$T_A = -40$ to 85°C $T_A = -55$ to 125°		Units
Symbol	raiameter		•00	Тур		Guaranteed L	imits	Units
t _r , t _f	Maximum Input Rise and		2.0V		1500	1500	1500	ns
	Fall Time, Clock		4.5V		500	500	500	ns
			6.0V		400	400	400	ns
t _{THL} , t _{TLH}	Maximum Output		2.0V	25	60	75	90	ns
	Rise and Fall Time		4.5V	6	12	15	18	ns
			6.0V	5	10	12	15	ns
C _{PD}	Power Dissipation			87				pF
	Capacitance (Note 5)							
C _{IN}	Maximum Input Capacitance			5	10	10	10	pF
C _{OUT}	Maximum Output Capacitance			15	20	20	20	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} sf + I_{CC}$.









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